Docket No.: 53074-025

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

RESPONSE UNDER 37 C.F.R. 1.116

EXPEDITED PROCEDURE

Tetsuzo UEDA

Serial No.: 09/904,129

Group Art Unit: 1765

Filed: July 11, 2001

Examiner: Matthew J. Song

For:

BUFFER LAYER AND GROWTH METHOD FOR SUBSEQUENT EPITAXIAL

GROWTH OF III-V NITRIDE SEMICONDUCTORS

AMENDMENT UNDER 37 C.F.R. 1.116

Commissioner for Patents Washington, DC 20231

Sir:

In response to the final Office Action dated April 3, 2003, having a three-month shortened statutory period for response set to expire on July 3, 2003, reconsideration of the above-identified application is respectfully requested in view of the following amendment and remarks.

I hereby certify that this paper is being facult to transmitted to the Peters, and Transmitted to the

on the data shows below.

Charles 1970

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